

Title (en)

MULTIBAND SEMICONDUCTOR COMPOSITIONS FOR PHOTOVOLTAIC DEVICES

Title (de)

MEHRBAND-HALBLEITERZUSAMMENSETZUNGEN FÜR PHOTOVOLTAISCHE BAUELEMENTE

Title (fr)

COMPOSITIONS DE SEMI-CONDUCTEURS MULTIBANDE POUR DISPOSITIFS PHOTOVOLTAIQUES

Publication

EP 1695388 A2 20060830 (EN)

Application

EP 04817004 A 20041129

Priority

- US 2004039900 W 20041129
- US 52621003 P 20031201

Abstract (en)

[origin: WO2005055285A2] The highly mismatched alloy $\text{Zn}_{1-y}\text{Mn}_y\text{OxTe}_{1-x}$ $0 \leq y < 1$ and $0 < x < 1$ and other Group II-IV-Oxygen implanted alloys have been synthesized using the combination of oxygen ion implantation and pulsed laser melting. Incorporation of small quantities of isovalent oxygen leads to the formation of a narrow, oxygen-derived band of extended states located within the band gap of the $\text{Zn}_{1-y}\text{Mn}_y\text{Te}$ host. With multiple band gaps that fall within the solar energy spectrum, $\text{Zn}_{1-y}\text{Mn}_y\text{OxTe}_{1-x}$ is a material perfectly satisfying the conditions for single junction photovoltaics with the potential for power conversion efficiencies surpassing 50%.

IPC 8 full level

H01L 29/00 (2006.01); **H01L 31/0296** (2006.01); **H01L 31/0304** (2006.01); **H01L 31/068** (2012.01)

IPC 8 main group level

H01L (2006.01)

CPC (source: EP)

H01L 31/02966 (2013.01); **H01L 31/03046** (2013.01); **H01L 31/068** (2013.01); **H01L 31/0693** (2013.01); **Y02E 10/544** (2013.01); **Y02E 10/547** (2013.01)

Citation (search report)

See references of WO 2005055285A2

Designated contracting state (EPC)

AT BE BG CH CY CZ DE DK EE ES FI FR GB GR HU IE IS IT LI LU MC NL PL PT RO SE SI SK TR

Designated extension state (EPC)

AL HR LT LV MK YU

DOCDB simple family (publication)

WO 2005055285 A2 20050616; **WO 2005055285 A3 20130110**; CN 101416321 A 20090422; CN 101853889 A 20101006; CN 101853889 B 20120704; CN 102738259 A 20121017; EP 1695388 A2 20060830; HK 1149366 A1 20110930; JP 2007535129 A 20071129

DOCDB simple family (application)

US 2004039900 W 20041129; CN 200480035510 A 20041129; CN 201010129583 A 20041129; CN 201210226587 A 20041129; EP 04817004 A 20041129; HK 11103441 A 20110406; JP 2006541490 A 20041129